

P-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
- 60	0.065 at V _{GS} = - 10 V	- 6.7		
	0.070 at V _{GS} = - 4.5 V	- 5.4		

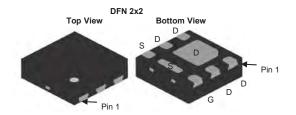
FEATURES

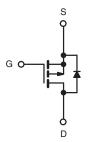
- DT-Trench Power MOSFET
- Fast Switching

Pb-free RoHS

APPLICATIONS

- Load Switches
- Half-Bridge Motor Drives
- High Voltage Non-Synchronous Buck Converters





P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T	A = 25 °C, unles	ss otherwise n	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 60		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current /T 150 °C\8	T _A = 25 °C	- I _D	- 6.7	- 4.6	Δ.
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 4.6	- 2.9	
Pulsed Drain Current		I _{DM}	- 30		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 3.2	- 1.3	
	T _A = 25 °C	- P _D	3.8	1.5	W
Maximum Power Dissipation ^a	T _A = 70 °C		2.0	0.8	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}			260		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maniana la destructo de Amelianda	t ≤ 10 s	- R _{thJA}	26	33		
Maximum Junction-to-Ambient ^a	Steady State		65	81	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.9	2.4		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. The DFN2X2 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.



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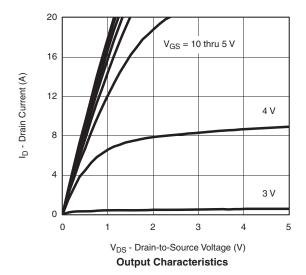
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 1		- 3	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	1	V _{DS} = - 60 V, V _{GS} = 0 V			- 1	
	I _{DSS}	V _{DS} = - 60 V, V _{GS} = 0 V, T _J = 70 °C			- 5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 20			Α
Drain-Source On-State Resistance ^a	В	V _{GS} = - 10 V, I _D = - 5.7 A	0.060		0.065	0
	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -4.4 \text{ A}$		0.070	0.076	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 5.7 A		11		S
Diode Forward Voltage ^a	V _{SD}	I _S = - 3.2 A, V _{GS} = 0 V		- 0.8	- 1.2	V
Dynamic ^b						
Total Gate Charge	Q_g			15	25	
Gate-Source Charge	Q_{gs}	V_{DS} = - 30 V, V_{GS} = - 10 V, I_D = - 5.7 A		4		nC
Gate-Drain Charge	Q_{gd}			3.2		
Turn-On Delay Time	t _{d(on)}			12	20	
Rise Time	t _r	V_{DD} = - 30 V, R_L = 30 Ω		12	20	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, $V_{GEN}=$ - 10 V, $R_g=6~\Omega$		22	35	ns
Fall Time	t _f			16	25	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 3.2 A, dl/dt = 100 A/μs		45	90	

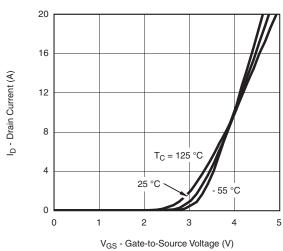
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

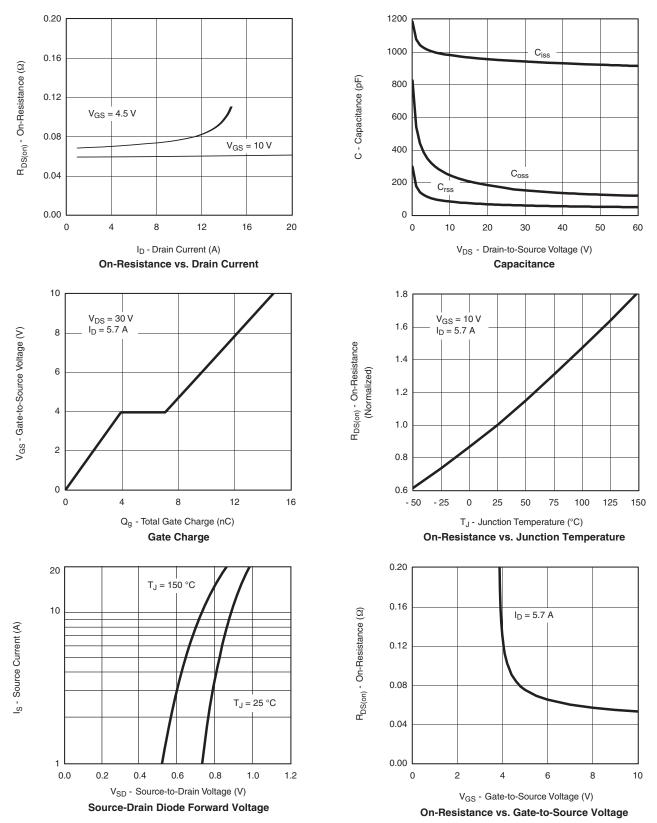




Transfer Characteristics

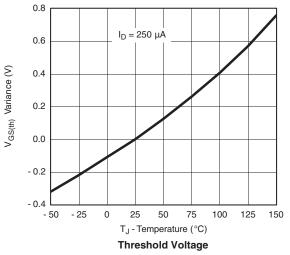


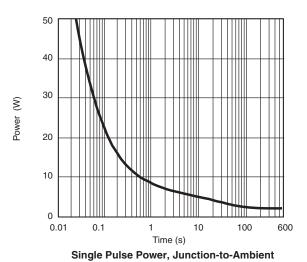
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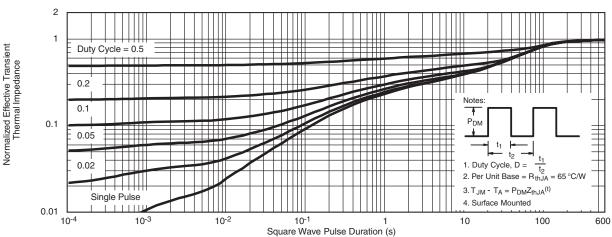


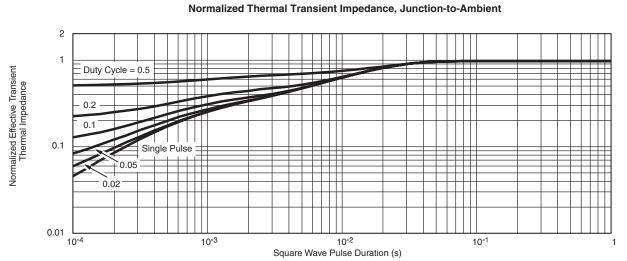


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted









Normalized Thermal Transient Impedance, Junction-to-Case





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